

February 2010

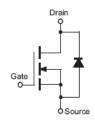
2N7002W

N-Channel Enhancement Mode Field Effect Transistor

Features

- · Low On-Resistance
- · Low Gate Threshold Voltage
- · Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Ultra-Small Surface Mount Package
- · Lead Free/RoHS Compliant





Absolute Maximum Ratings * T_A = 25°C unless otherwise noted

Symbol	Parameter		Value	Units	
V _{DSS}	Drain-Source Voltage		60	V	
V_{DGR}	Drain-Gate Voltage $R_{GS} \le 1.0 M\Omega$		60	V	
V _{GSS}	Gate-Source Voltage	Continuous Pulsed	±20 ±40	V	
I _D	Drain Current	Continuous Continuous @ 100°C Pulsed	115 73 800	mA	
T_{J} , T_{STG}	Junction and Storage Temperature Range		-55 to +150	°C	

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may by impaired.

Thermal Characteristics

Symbol	Parameter	Value	Units
P _D	Total Device Dissipation Derating above T _A = 25°C	200 1.6	mW mW/°C
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient *	625	°C/W

^{*} Device mounted on FR-4 PCB, 1 inch x 0.85 inch x 0.062 inch. Minimum land pad size.

Electrical Characteristics $T_A = 25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
Off Charac	teristics (Note1)					
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =10uA	60	78	-	V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =60V, V _{GS} =0V V _{DS} =60V, V _{GS} =0V, @T _C =125°C	-	0.001 7	1.0 500	μА
I _{GSS}	Gate-Body Leakage	V_{GS} =±20V, V_{DS} =0V	-	0.2	±10	nA
On Charact	teristics (Note1)					
V _{GS(th)}	Gate Threshold Voltage	$V_{DS}=V_{GS}$, $I_{D}=250\mu A$	1.0	1.76	2.0	V
R _{DS(ON)}	Static Drain-Source On-Resistance	V _{GS} =5V, I _D =0.05A, V _{GS} =10V, I _D =0.5A, @T _J =125°C		1.6 2.53	7.5 13.5	Ω
I _{D(ON)}	On-State Drain Current	V _{GS} =10V, V _{DS} =7.5V	0.5	1.43	-	Α
9 _{FS}	Forward Transconductance	V _{DS} =10V, I _D =0.2A	80	356.5	-	mS
Dynamic C	Characteristics					
C _{iss}	Input Capacitance		-	37.8	50	pF
C _{oss}	Output Capacitance	V _{DS} =25V, V _{GS} =0V, f=1.0MHz	-	12.4	25	pF
C _{rss}	Reverse Transfer Capacitance		-	6.5	7.0	pF
Switching	Characteristics					
t _{D(ON)}	Turn-On Delay Time	V _{DD} =30V, I _D =0.2A, V _{GEN} =10V	-	5.85	20	no
t _{D(OFF)}	Turn-Off Delay Time	$R_L=150\Omega$, $R_{GEN}=25\Omega$	-	12.5	20	ns

Note1: Short duration test pulse used to minimize self-heating effect.

Typical Performance Characteristics

Figure 1. On-Region Characteristics

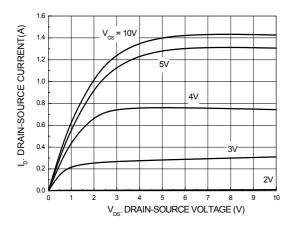


Figure 3. On-Resistance Variation with Temperature

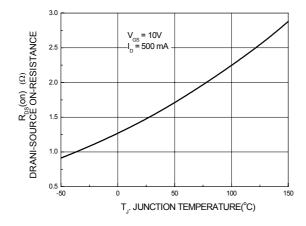


Figure 5. Transfer Characteristics

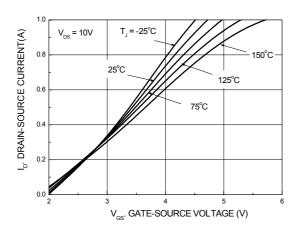


Figure 2. On-Resistance Variation with Gate Voltage and Drain Current

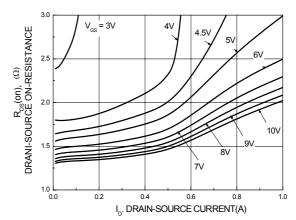


Figure 4. On-Resistance Variation with Gate-Source Voltage

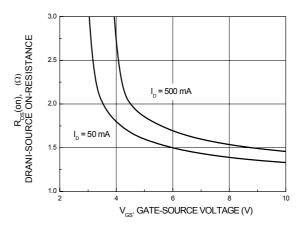
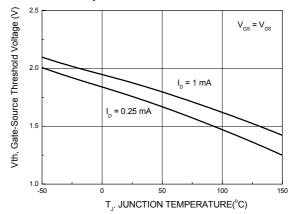


Figure 6. Gate Threshold Variation with Temperature



Typical Performance Characteristics

Figure 7. Reverse Drain Current Variation with Diode Forward Voltage and Temperature

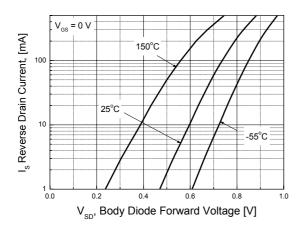
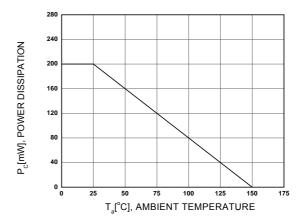
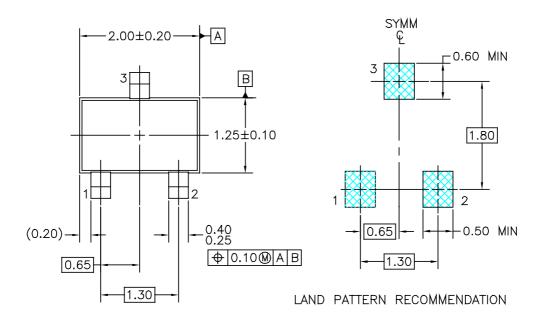


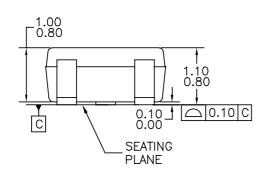
Figure 8. Power Derating

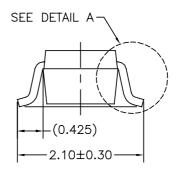


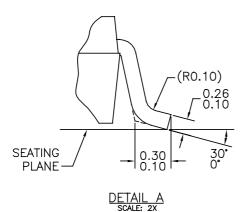
Package Dimensions

SOT323









NOTES: UNLESS OTHERWISE SPECIFIED

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Definition of Terms			
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